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Authors

Tien, Ming-Chun
Mizumoto, Tetsuya
Pintus, Paolo
et al.

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Silicon ring isolators with bonded nonreciprocal magneto-optic garnets

Ming-Chun Tien,^{1,*} Tetsuya Mizumoto,² Paolo Pintus,^{1,3}
Herbert Kromer,¹ and John E. Bowers¹

¹Department of Electrical and Computer Engineering, University of California, Santa Barbara, CA 93106, USA

²Department of Electrical and Electronic Engineering, Tokyo Institute of Technology, Tokyo, Japan

³Scuola Superiore Sant'Anna, 56124, Pisa, Italy

*mctien101@gmail.com

Abstract: A ring isolator is demonstrated for the first time by directly bonding a cerium-substituted yttrium iron garnet (Ce:YIG) onto a silicon ring resonator using oxygen plasma enhanced bonding. The silicon waveguide is 600 nm wide and 295 nm thick with 500-nm-thick Ce:YIG on the top to have reasonable nonreciprocal effect and low optical loss. With a radial magnetic field applied to the ring isolator, it exhibits 9-dB isolation at resonance in the 1550 nm wavelength regime.

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OCIS codes: (230.3240) Isolators; (160.3820) Magneto-optical materials.

References and links

1. T. Shintaku, "Integrated optical isolator based on efficient nonreciprocal radiation mode conversion," *Appl. Phys. Lett.* **73**(14), 1946–1948 (1998).
2. H. Shimizu and S. Goto, "Evanescent semiconductor active optical isolators for low insertion loss and high gain saturation power," *J. Lightwave Technol.* **28**(9), 1414–1419 (2010).
3. H. Shimizu and Y. Nakano, "Fabrication and characterization of an InGaAsP/InP active waveguide optical isolator with 14.7 dB/mm TE mode nonreciprocal attenuation," *J. Lightwave Technol.* **24**(1), 38–43 (2006).
4. J. Fujita, M. Levy, R. M. Osgood, Jr., L. Wilkens, and H. Dotsch, "Waveguide optical isolator based on Mach-Zehnder interferometer," *Appl. Phys. Lett.* **76**(16), 2158–2160 (2000).
5. H. Yokoi, T. Mizumoto, and Y. Shoji, "Optical nonreciprocal devices with a silicon guiding layer fabricated by wafer bonding," *Appl. Opt.* **42**(33), 6605–6612 (2003).
6. H. Yokoi, T. Mizumoto, N. Shinjo, N. Futakuchi, and Y. Nakano, "Demonstration of an optical isolator with a semiconductor guiding layer that was obtained by use of a nonreciprocal phase shift," *Appl. Opt.* **39**(33), 6158–6164 (2000).
7. Y. Shoji, T. Mizumoto, H. Yokoi, I. W. Hsieh, and R. M. Osgood, "Magneto-optical isolator with silicon waveguides fabricated by direct bonding," *Appl. Phys. Lett.* **92**(7), 071117 (2008).
8. Z. Wang and S. Fan, "Optical circulators in two-dimensional magneto-optical photonic crystals," *Opt. Lett.* **30**(15), 1989–1991 (2005).
9. W. Śmigaj, J. Romero-Vivas, B. Gralak, L. Magdenko, B. Dagens, and M. Vanwolleghem, "Magneto-optical circulator designed for operation in a uniform external magnetic field," *Opt. Lett.* **35**(4), 568–570 (2010).
10. A. Rostami, "Piecewise linear integrated optical device as an optical isolator using two-port nonlinear ring resonators," *Opt. Laser Technol.* **39**(5), 1059–1065 (2007).
11. L. Fan, J. Wang, H. Shen, L. T. Varghese, B. Niu, J. Ouyang, and M. Qi, "A CMOS compatible microring-based on-chip isolator with 18dB optical isolation," in *Frontiers in Optics* (OSA, 2010), paper FThQ4.
12. Z. Yu and S. Fan, "Complete optical isolation created by indirect interband photonic transitions," *Nat. Photonics* **3**(2), 91–94 (2009).
13. N. Kono, K. Kakihara, K. Saitoh, and M. Koshiba, "Nonreciprocal microresonators for the miniaturization of optical waveguide isolators," *Opt. Express* **15**(12), 7737–7751 (2007).
14. S. Yamamoto and T. Makimoto, "Circuit theory for a class of anisotropic and gyrotropic thin-film optical waveguides and design of nonreciprocal devices for integrated optics," *J. Appl. Phys.* **45**(2), 882–888 (1974).
15. O. Zhuromskyy, H. Dotsch, M. Lohmeyer, L. Wilkens, and P. Hertel, "Magneto-optical waveguides with polarization-independent nonreciprocal phase shift," *J. Lightwave Technol.* **19**(2), 214–221 (2001).
16. A. B. Fallahkhair, K. S. Li, and T. E. Murphy, "Vector finite difference modesolver for anisotropic dielectric waveguides," *J. Lightwave Technol.* **26**(11), 1423–1431 (2008).
17. P. Paolo, M.-C. Tien, and J. Bowers, "Design of magneto-optical ring isolator on SOI based on the finite element method," *Photon. Technol. Lett.* (submitted to).
18. A. Konrad, "High-order triangular finite elements for electromagnetic waves in anisotropic media," *IEEE Trans. Microw. Theory Tech.* **25**(5), 353–360 (1977).

19. T. Shintaku, T. Uno, and M. Kobayashi, "Magneto-optic channel waveguides in Ce-substituted yttrium iron garnet," *J. Appl. Phys.* **74**(8), 4877–4881 (1993).
 20. D. Pasquariello and K. Hjort, "Plasma-assisted InP-to-Si low temperature wafer bonding," *IEEE J. Sel. Top. Quantum Electron.* **8**(1), 118–131 (2002).
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1. Introduction

The need for higher capacity and lower cost optical networks is driving the development of photonic integrated circuits with various functions, such as lasing, modulation, switching, splitting, and detection. Optical isolation is especially important to reduce unwanted optical reflection back to semiconductor lasers, but is not yet a part of these integrated functions. Conventional optical isolators, which consist of a Faraday rotator and a pair of polarizers, are bulky and difficult to integrate. Several waveguide-type isolators have been explored for integration of isolators.

Waveguide optical isolators use magneto-optic (MO) material, such as iron, cobalt, or yttrium iron garnet (YIG), to generate a nonreciprocal effect with the existence of an external magnetic field. The optical isolation can be achieved by nonreciprocal mode conversion [1], nonreciprocal waveguide loss [2,3], and nonreciprocal phase shift [4,5]. The isolator utilizing nonreciprocal mode conversion can convert backward light to a radiation mode and result in higher optical loss, but phase matching between the modes is always an issue. Semiconductor amplifiers (SOAs) combined with MO material with nonreciprocal loss can suppress the backward light while providing gain to compensate the loss of the forward light. However, the SOA requires continuous power consumption to compensate the extra insertion loss due to the lossy MO material. Proper Mach-Zehnder Interferometer (MZI) design with nonreciprocal phase shift generates constructive interference for forward light and destructive interference for backward light to realize optical isolation. The MZI optical isolators have been demonstrated on both III-V and silicon platforms [6,7].

Alternatively, resonant cavities, such as MO photonic crystals and ring resonators, can be designed as optical isolators to reduce the footprint of devices at the expense of isolation bandwidth. The isolators using MO photonic crystals require either precise magnetization domain control over micron scale [8] or complex design of photonic crystals [9]. These issues make them difficult to be experimentally realized. Using a nonlinear effect, optical isolation was demonstrated based on ring resonators [10,11]. However, they have specific operation power. In addition, optical isolation doesn't happen with forward and backward light launched simultaneously for these devices, and this is usually the case of required optical isolation for semiconductor lasers. Another novel concept replying on temporal refractive-index modulation is proposed to realize nonreciprocal frequency conversion using a non-magnetic ring resonator [12]. The optical isolation can be achieved by incorporating an optical filter with this nonreciprocal frequency converter.

2. Nonreciprocal ring resonator

The concept of nonreciprocal ring resonators was first proposed by Kono in 2007 [13]. However, the proposed structure is difficult to be realized in a practical approach. In this paper we propose a simplified structure and demonstrate silicon optical ring isolators with bonded MO garnets for the first time. The isolator consists of a ring resonator, a straight coupled-waveguide, and a bonded MO garnet as shown in Fig. 1. In our experiment, cerium-substituted yttrium iron garnet (Ce:YIG) is used as the MO material because of its high Faraday coefficient and low optical loss in the 1550 nm regime. By applying a radial magnetic field centered at the ring resonator, the nonreciprocal effect breaks the symmetry of the ring resonator. As a result, the clockwise (CW)- and counterclockwise (CCW)- propagating modes have different propagation constants and thus different resonance wavelengths. With a straight waveguide coupled to the ring resonator, the forward light from the input is coupled to the CW mode while the backward light is coupled to the CCW mode. If the transmission spectra for the forward and backward directions are offset by half of the free spectral range, optical

isolation can be realized and optimized. With the optical input at off-resonance wavelength of the CW mode and at on-resonance wavelength of the CCW mode, the forward light is transmitted while the backward light is filtered out to realize optical isolation.

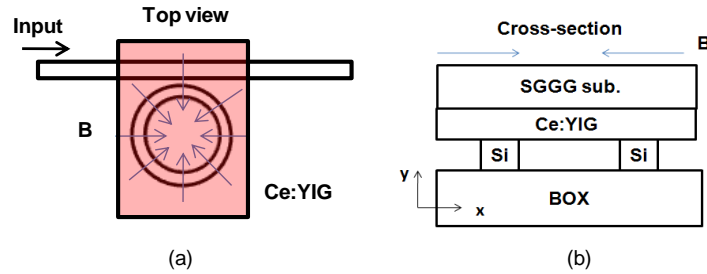


Fig. 1. Schematic of a ring isolator consisting of a ring resonator, a straight waveguide and a bonded Ce:YIG layer as magneto-optic material. (a) top view (b) cross-section.

The propagation constant difference between CW and CCW modes with existence of an external magnetic field is written as [14,15]

$$\Delta\beta = \omega\epsilon_0 \frac{\iint \vec{E}^* \Delta\epsilon \vec{E} dx dy}{\iint \left[\vec{E} \times \vec{H}^* + \vec{E}^* \times \vec{H} \right]_z dx dy}, \quad (1)$$

where \vec{E} and \vec{H} are the electrical and magnetic field, $\Delta\epsilon$ is off-diagonal permittivity tensor of MO material, and ϵ_0 is the permittivity of MO material. The electrical and magnetic field distributions are numerically solved by incorporating vectorial finite-difference algorithm into MATLAB [16]. Figure 2(a) shows the calculated H_x distribution profile of a 600-nm-wide and 300-nm-thick silicon waveguide with 500-nm-thick Ce:YIG as upper cladding and SiO_2 as lower cladding. Once the field distribution in the waveguide and Faraday coefficient of Ce:YIG are known, the resonance wavelength split due to the propagation constant difference between CW and CCW modes can be derived from Eq. (1). We also compare the analytic solution with the simulation results using numerical full-vectorial finite element method [17,18] as shown in Fig. 2(b). The results are slightly different probably because the mode solver used for analytic solution doesn't consider the small refractive index change due to the nonreciprocal effect. Both methods indicate the maximum nonreciprocal effect as the silicon waveguide thickness is approximately 220 nm. However, thinner waveguides result in higher waveguide loss from the Ce:YIG layer, which has optical loss of 10-15 dB/cm. Therefore, there is a trade-off between the nonreciprocal effect and the waveguide loss. The waveguide thickness is chosen at 295 nm to have reasonable nonreciprocal effect and low optical loss in our design.

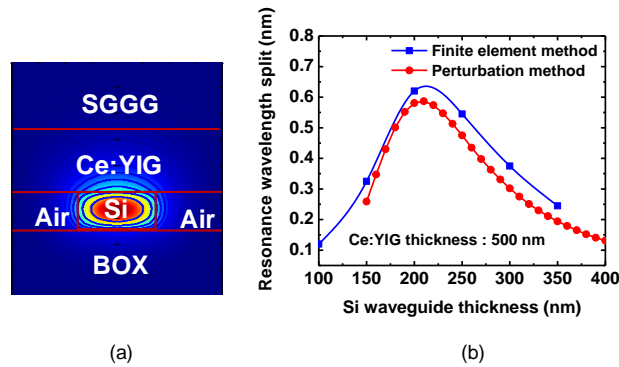


Fig. 2. (a) Calculated H_x field distribution in a 600 nm by 300 nm silicon waveguide with 500-nm-thick Ce:YIG as upper cladding and silicon dioxide as lower cladding. (b) Resonance wavelength split of the ring resonator as a function of waveguide thickness due to the nonreciprocal effect. The Faraday coefficient used for calculation is 4000 $^{\circ}$ /cm.

3. Fabrication and characterization of ring isolators

Silicon rectangular waveguides and ring resonators are fabricated on a silicon-on-insulator (SOI) wafer with a 295-nm-thick silicon device layer and a 3- μ m-thick buried oxide layer using electron-beam lithography. The waveguide width is 600 nm, the ring radius is 900 μ m, and the gap between the ring and the waveguide is 250 nm. 500-nm-thick Ce:YIG is grown on a (Ca, Mg, Zr)-substituted gadolinium gallium garnet (SGGG) substrate as MO material to generate the nonreciprocal effect. The Ce:YIG has a Faraday-rotation coefficient as large as -4500 deg/cm at 1550 nm wavelength regime [19]. The Ce:YIG on an SGGG substrate is then bonded to the fabricated silicon ring resonators using the following oxygen plasma assisted low temperature bonding technique [7,20]. Both silicon and Ce:YIG are cleaned in solvent followed by 20-minute ozone exposure. The cleaned silicon and Ce:YIG surfaces are then activated by oxygen plasma. The activated surfaces are immediately soaked in NH_4OH vapor for two minutes to be terminated with OH groups. At this point, the samples are attached to each other with assistance of a proper fixture to generate an external pressure of 3MPa. The whole fixture together with samples is annealed at 250 $^{\circ}$ C for 1 hour to have a strong bond. Higher annealing temperature causes sample cracking due to the mismatch of thermal expansion coefficients between silicon and Ce:YIG.

The crystallinity of the 500-nm-thick Ce:YIG film on an SGGG substrate was investigated using Rigaku Smartlab High Resolution X-ray Diffractometer. The measured diffraction curve of the thin film is shown in the solid line of Fig. 3(a) while the dashed line shows the diffraction curve of the substrate only. Because the crystal orientation of the SGGG substrate is in (111) direction, Ce:YIG also grows in the (111) direction. Ce:YIG has a cubic crystal structure with a lattice constant of 1.253 nm, whose corresponding X-ray diffraction peak is approximately at 50.4 degree as shown in Fig. 3(a). The X-ray diffraction also exhibits the crystal structure of the SGGG substrate, which has lattice constant of 1.249 nm. It should be noted that all the peaks are composed by $K_{\alpha 1}$ and $K_{\alpha 2}$ peaks due to multi-wavelengths of the X-ray source.

The magnetization of Ce:YIG was also investigated using a Quantum Design superconducting quantum interference device (SQUID) magnetometer. The magnetization versus magnetic field strength was measured at room temperature with a sample size of 5 mm by 5 mm. The measured curve consists of the ferromagnetic Ce:YIG layer and the paramagnetic SGGG substrate. Figure 3(b) shows the curves after subtracting the contribution from the substrate. The saturation magnetization is estimated to be ~ 40 emu/cm 3 with external magnetic field strength larger than 50 Oe. This implies that the required external magnetic flux density to saturate the film is ~ 50 Gauss.

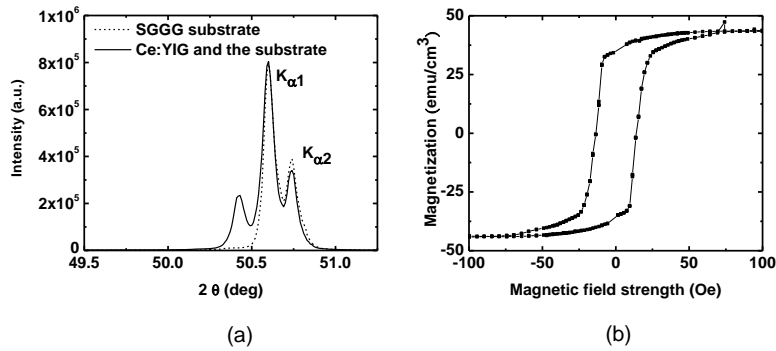


Fig. 3. (a) X-ray diffraction measurement of 500-nm-thick Ce:YIG and SGGG substrates. (b) Hysteretic magnetization of Ce:YIG measured using a Quantum Design superconducting quantum interference device (SQUID).

The fabricated ring isolator is characterized by measuring the transmission spectra with TM-polarized optical input through a lensed fiber. In order to have a nonreciprocal effect, the Ce:YIG layer has to be magnetized with a radial external magnetic field centered at the origin of the ring isolator. The magnetic field is applied by positioning an axially magnetized neodymium cylinder magnet on the top of the ring. The diameter of the magnet (1.6 mm) is slightly smaller than that of the ring isolator (1.8 mm), and as a result, the direction of the magnet field above the ring is in inward or outward radial direction depending on the pole of the magnet (Fig. 4). Figure 5(a) shows a set of transmission spectra indicating the resonance wavelength shift while the distance between the magnet and the garnet gradually changes. The maximum wavelength shift we obtained experimentally is 0.1 nm when the magnet is physically in contact with the garnet. A larger wavelength shift is expected, as indicated in Fig. 2(b), with a thinner garnet substrate that allows a stronger magnetic field to the Ce:YIG layer and thus saturates the film. With a proper intensity of external magnetic field, the transmission spectrum difference for opposite magnetic field directions can be adjusted equal to half of the free spectral range, which is the optimal operation condition as a ring isolator, as shown in Fig. 5(b). This is equivalent to the situation of different optical propagation directions with a fixed magnetic field. Because of the nonreciprocal effect of the ring resonator with a Ce:YIG layer, the resonance wavelength of the ring shifts. The wavelength shift is proportional to the magnitude of the magnetic field until the Ce:YIG saturates with the field strength larger than 50 Oe as shown in Fig. 3(b). By applying a proper external magnetic field to the ring isolator, the offset of the transmission spectra for different propagation directions can be adjusted to be half of the free spectral range, and it results in an isolation ratio of about 9 dB. A transmission spectrum of the ring resonator before bonding with Ce:YIG is shown in Fig. 5(c) for comparison.

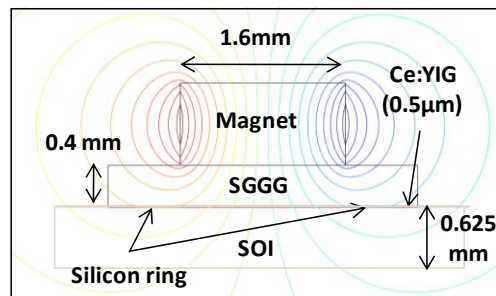


Fig. 4. Calculated magnetic flux density using COMSOL.

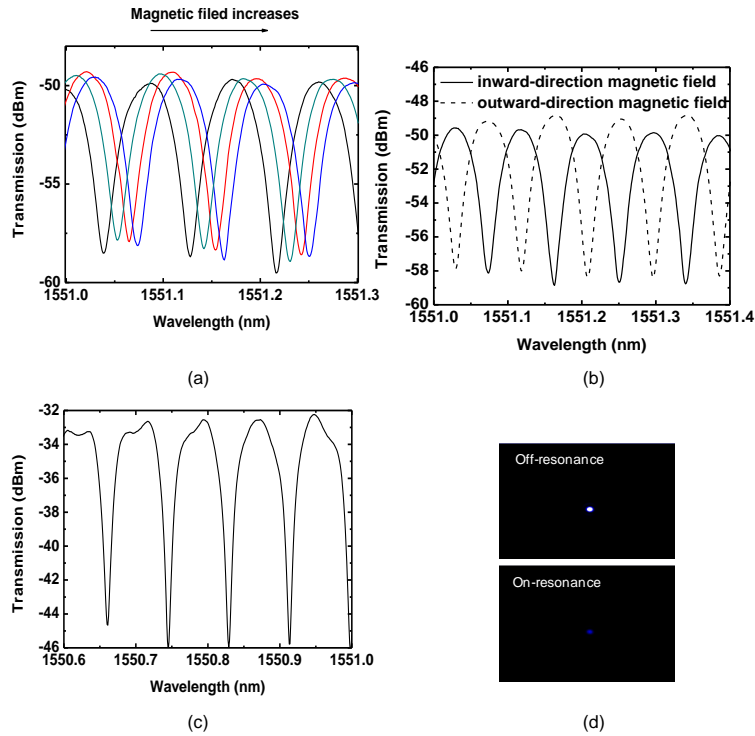


Fig. 5. (a) Transmission spectra of the ring isolator with external radial magnetic fields in different directions. (b) Transmission spectrum of the ring resonator before bonding with Ce:YIG. (c) Near field infrared image at the waveguide output facet with different directions of fields at 1551.25 nm.

There are two reasons the isolation ratio of the ring isolator is limited. The first one is that the power coupling ratio from the straight waveguide to the ring resonator is not optimized to the critical coupling region, which has largest extinction ratio. This can be resolved by designing the waveguide-to-ring coupling in the critical coupling region. The other is that the resonator loss increases after bonding Ce:YIG on the ring, and thus the adjacent resonance dips in the spectrum broaden and overlap with each other. The size of the ring can also be further reduced to increase the free spectra range. As a result, the overlap of the two adjacent resonance dips can be avoided and thus the isolation ratio of the ring isolator won't be cut-off.

4. Conclusions

In summary, we demonstrated the first nonreciprocal ring resonator by bonding Ce:YIG, on top of a silicon ring resonator. The nonreciprocal ring resonator can be used as a ring isolator, which has the advantages of miniaturization and integration with other optoelectronic devices, especially with semiconductor lasers. A 9-dB isolation ratio is achieved in 1550 nm regime and it can be further improved by proper design of waveguide-to-ring power coupling ratio in the critical coupling regime.

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